



#### PNP PRE-BIASED DUAL TRANSISTOR IN SOT363

#### **Features**

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDC)
- Built-In Biasing Resistors

DDA114EU

- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DDA (XXXX) UQ are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Part Number	R1 (NOM)	R2 (NOM)
DDA124EU	22kΩ	22kΩ
DDA144EU	47kΩ	47kΩ
DDA114YU	10kΩ	47kΩ
DDA123JU	2.2kΩ	47kΩ

10kΩ

## **Mechanical Data**

- Package: SOT363
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (83)
- Weight: 0.006 grams (Approximate)

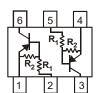
Part Number	R1 Only
DDA113TU	1kΩ
DDA143TU	4.7kΩ
DDA114TU	10kΩ



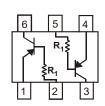
10kΩ







R1. R2



R1 Only

Device Schematic

### Ordering Information (Notes 4, 5)

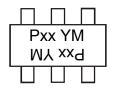
Orderable Part Number	Status	Dookogo	Mauking	Reel Size	Tape Width	Pack	ing
Orderable Part Number	Status	Package	Marking	(inches)	(mm)	Qty.	Carrier
DDA124EU-7-F	Active	SOT363	P17	7	8	3,000	Reel
DDA124EUQ-7-F	Active	SOT363	P17	7	8	3,000	Reel
DDA124EUQ-13-F	Active	SOT363	P17	13	8	10,000	Reel
DDA144EU-7-F	Active	SOT363	P20	7	8	3,000	Reel
DDA144EUQ-7-F	Active	SOT363	P20	7	8	3,000	Reel
DDA114YU-7-F	Active	SOT363	P14	7	8	3,000	Reel
DDA114YUQ-7-F	NRND (Use ADA114YUQ)	SOT363	P14	7	8	3,000	Reel
DDA123JU-7-F	Active	SOT363	P06	7	8	3,000	Reel
DDA114EU-7-F	Active	SOT363	P13	7	8	3,000	Reel
DDA114EUQ-7-F	NRND (Use ADA114EUQ)	SOT363	P13	7	8	3,000	Reel
DDA113TU-7-F	Active	SOT363	P01	7	8	3,000	Reel
DDA143TU-7-F	Active	SOT363	P07	7	8	3,000	Reel
DDA143TUQ-7-F	Active	SOT363	P07	7	8	3,000	Reel
DDA143TUQ-13-F	Active	SOT363	P07	13	8	10,000	Reel
DDA114TU-7-F	Active	SOT363	P12	7	8	3,000	Reel
DDA114TUQ-7-F	Active	SOT363	P12	7	8	3,000	Reel
DDA114TUQ-13-F	Active	SOT363	P12	13	8	10,000	Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.
- 5. NRND = Not Recommended for New Design.



## **Marking Information**



Pxx = Product Type Marking Code (See *Ordering Information*) YM = Date Code Marking

Y or  $\overline{Y}$ = Year (ex: M = 2025) M = Month (ex: O = October)

Date Code Key

Year	2002	-	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	0	-	М	N	Р	R	S	T	U	V	W	Χ
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

# Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage (1) to (6) and (4) to (3)		Vcc	-50	V
Input Voltage (1) to (2) and (4) to (5)	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU DDA113TU DDA143TU DDA114TU	Vin	+10 to -40 +10 to -40 +6 to -40 +5 to -12 +10 to -40 +5V Max +5V Max +5V Max	<b>V</b>
Output Current	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU DDA113TU DDA143TU DDA114TU	lo	-30 -30 -70 -100 -50 -100 -100	mA
Output Current	•	I <sub>C(max)</sub>	-100	mA

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 6, 7)	PD	200	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	Reja	625	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Notes:

- 6. Mounted on FR-4 PC Board with minimum recommended pad layout. 7. 150mW per element must not be exceeded.



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic (DDA113TU & DDA143TU & DDA114TU Only)	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	-50	_	_	V	Ic = -50μA
Collector-Emitter Breakdown Voltage	BVceo	-50	_	_	V	Ic = -1mA
Emitter-Base Breakdown Voltage	BVEBO	-5	_	_	V	I <sub>E</sub> = -50μA
Collector Cutoff Current	Ісво	_	_	-0.5	μA	V <sub>CB</sub> = -50V
Emitter Cutoff Current	I <sub>ЕВО</sub>	_	_	-0.5	μA	V <sub>EB</sub> = -4V
Collector-Emitter Saturation Voltage	VCE(sat)	_	_	-0.3	V	Ic/IB = -2.5mA / -0.25mA DDA143TU Ic/IB = -1mA / -0.1mA DDA114TU Ic/IB = -10mA / -1mA DDA113TU
DC Current Transfer Ratio	hfE	100 160	250 —	600 600	_	I <sub>C</sub> = -1mA, V <sub>CE</sub> = -5V I <sub>C</sub> = -1mA, V <sub>CE</sub> = -5V DDA143TU/Q
Input Resistor (R <sub>1</sub> ) Tolerance	ΔR1	-30	_	+30	%	_
Gain-Bandwidth Product (Note 8)	f⊤	_	250	_	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = 5mA, f = 100MHz

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
In a stable and	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	VI(off)	-0.5 -0.5 -0.3 -0.5	-1.1 -1.1 — — -1.1		٧	Vcc = -5V, Io = -100μA
Input Voltage	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	VI(on)	_	-1.9 -1.9 — — — –1.9	-3.0 -3.0 -1.4 -1.1 -3.0	<b>V</b>	$V_0 = -0.3V$ , $I_0 = -5mA$ $V_0 = -0.3V$ , $I_0 = -2mA$ $V_0 = -0.3V$ , $I_0 = -1mA$ $V_0 = -0.3V$ , $I_0 = -5mA$ $V_0 = -0.3V$ , $I_0 = -10mA$
Output Voltage	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	VO(on)	_	-0.1	-0.3	V	Io/I <sub>I</sub> = -10mA / -0.5mA I <sub>O</sub> /I <sub>I</sub> = -10mA / -0.5mA I <sub>O</sub> /I <sub>I</sub> = -5mA / -0.25mA I <sub>O</sub> /I <sub>I</sub> = -5mA / -0.25mA I <sub>O</sub> /I <sub>I</sub> = -10mA / -0.5mA
Input Current	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	lı	_	ı	-0.36 -0.18 -0.88 -3.6 -0.88	mA	V <sub>I</sub> = -5V
Output Current		I <sub>O(off)</sub>	_	_	-0.5	μΑ	V <sub>CC</sub> = -50V, V <sub>I</sub> = 0
DC Current Gain	DDA124EU DDA124EUQ DDA144EU DDA114YU DDA123JU DDA114EU	G	56 60 68 68 80 30	_		_	Vo = -5V, Io = -5mA Vo = -5V, Io = -5mA Vo = -5V, Io = -5mA Vo = -5V, Io = -10mA Vo = -5V, Io = -10mA Vo = -5V, Io = -5mA
Input Resistor (R <sub>1</sub> ) Tolerance		$\Delta R_1$	-30	_	+30	%	_
Resistance Ratio Tolerance		R <sub>2</sub> /R <sub>1</sub>	-20	_	+20	%	
Gain-Bandwidth Product (Note 8	)	f⊤	_	250	_	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = -5mA, f = 100MHz

Note: 8. Transistor - For Reference Only.



# Typical Curves - DDA123JU (@T<sub>A</sub> = +25°C, unless otherwise specified.)

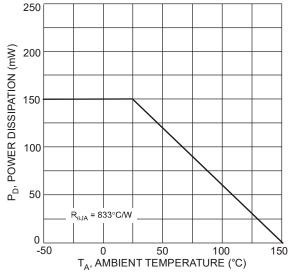


Fig. 1 Power Dissipation vs. Ambient Temperature

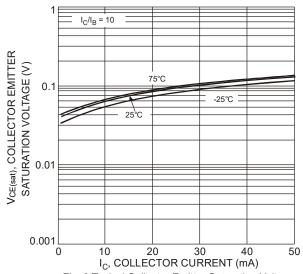


Fig. 3 Typical Collector Emitter Saturation Voltage vs. Collector Current

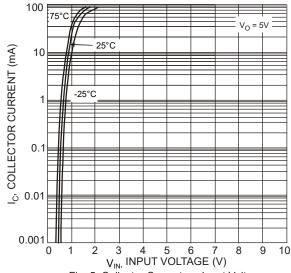


Fig. 5 Collector Current vs. Input Voltage

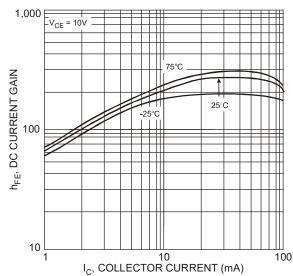


Fig. 2 Typical DC Current Gain vs. Collector Current

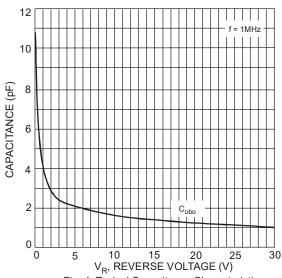


Fig. 4 Typical Capacitance Characteristics

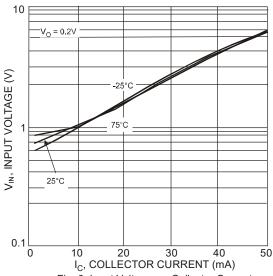
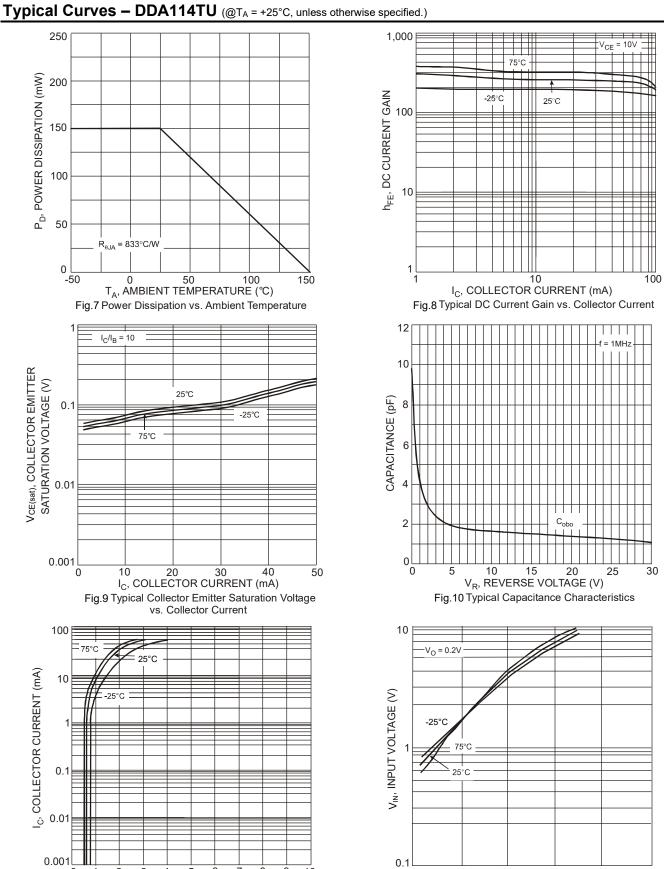


Fig. 6 Input Voltage vs. Collector Current





3 4 5 6 7 V<sub>IN</sub>, INPUT VOLTAGE (V)

Fig.11Collector Current vs. Input Voltage

0

10

50

10 20 30 40  $I_{\rm C}$ , COLLECTOR CURRENT (mA)

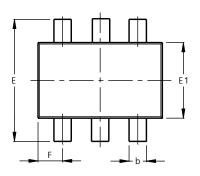
Fig.12 Input Voltage vs. Collector Current

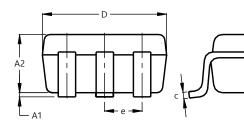


## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT363**



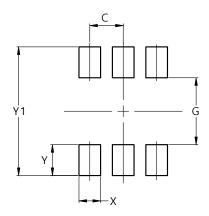


SOT363						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.10	0.30	0.25			
С	0.10	0.22	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	C	.650 E	SC			
F	0.40	0.45	0.425			
L	0.25	0.40	0.30			
а	0°	8°				
All	Dimen	sions	in mm			

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT363**



Dimensions	Value			
Dillicitorio	(in mm)			
C	0.650			
G	1.300			
X	0.420			
Υ	0.600			
Y1	2.500			



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